# NSN 5962-01-387-3960

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# Maximum Power Dissipation Rating:

1.2 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Hermetically sealed and burn in and programmed

# Inclosure Material:

Ceramic

# Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Complementary-metal oxide-semiconductor logic

#### Case Outline Source And Designator:

C-4 mil-m-38510

#### **Current Rating Per Characteristic:**

15.00 milliamperes reverse current, dc absolute

#### **Terminal Surface Treatment:**

Solder

# Voltage Rating And Type Per Characteristic:

7.0 volts power source

# **Time Rating Per Chacteristic:**

40.00 nanoseconds delay

#### Memory Device Type:

Pal

#### **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### **Terminal Type And Quantity:**

24 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

Fiig:

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